

40 V, 600 mA, double NPN switching transistor 2 July 2015 Pro

Product data sheet

1. General description

Double NPN switching transistor in a very small SOT363 (TSSOP6) Surface-Mounted Device (SMD) plastic package.

Double PNP complement: PMBT4403YS

2. Features and benefits

- Double general-purpose switching transistor
- High current (max. 600 mA)
- Voltage max. 40 V
- AEC-Q101 qualified

3. Applications

• Switching and linear amplification

4. Quick reference data

Table 1. Qui	ck reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per transistor						
V _{CEO}	collector-emitter voltage	open base	-	-	40	V
I _C	collector current		-	-	600	mA
Per transistor					1	
h _{FE}	DC current gain	V_{CE} = 1 V; I _C = 150 mA; t _p ≤ 300 µs; $\delta \le 0.02$; T _{amb} = 25 °C	100	-	300	
		$\label{eq:Vce} \begin{split} &V_{CE} = 2 \;V; \; I_{C} = 500 \;mA; \; t_{p} \leq 300 \;\mus; \\ &\delta \leq 0.02; \; T_{amb} = 25 \;^{\circ}C \end{split}$	40	-	-	



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5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E	emitter TR1		6 5 4
2	В	base TR1		
3	С	collector TR2		$\begin{pmatrix} TR1 \\ TR1 \end{pmatrix}$
4	E	emitter TR2		
5	В	base TR2	TSSOP6 (SOT363)	1 2 3
6	С	collector TR1		sym020

6. Ordering information

Table 3. Ordering information					
Type number	Package				
	Name	Description	Version		
PMBT4401YS	TSSOP6	plastic surface-mounted package; 6 leads	SOT363		

7. Marking

Table 4. Marking codes	
Type number	Marking code
	[1]
PMBT4401YS	BG%

[1] % = placeholder for manufacturing site code

8. Limiting values

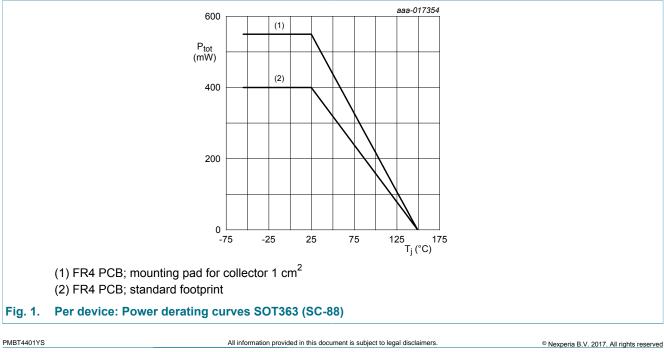
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Мах	Unit
Per transis	tor					
V _{CBO}	collector-base voltage	open emitter		-	60	V
V _{CEO}	collector-emitter voltage	open base		-	40	V
V _{EBO}	emitter-base voltage	open collector		-	6	V
I _C	collector current			-	600	mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	800	mA
I _{BM}	peak base current			-	200	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	250	mW
			[2]	-	300	mW
Per device						
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	400	mW
			[2]	-	550	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB); single-sided copper; tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB; single-sided copper; tin-plated and mounting pad for collector 1 cm².



9. Thermal characteristics

Table 6. The	rmal characteristics							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
Per transistor								
R _{th(j-a)}	thermal resistance	in free air [1]	[1]	-	-	500	K/W	
	from junction to ambient			-	-	417	K/W	
Per device		- I						
R _{th(j-a)}	thermal resistance	in free air	[1]	-	-	313	K/W	
	from junction to ambient		[2]	-	-	227	K/W	

[1] Device mounted on an FR4 PCB; single-sided copper; tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB; single-sided copper; tin-plated and mounting pad for collector 1 cm².

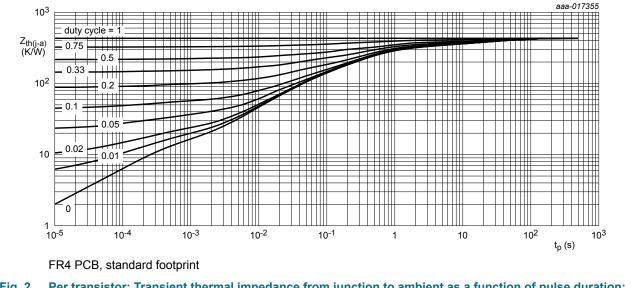
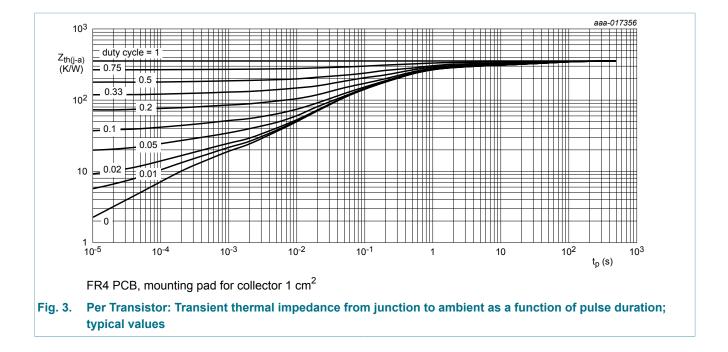


Fig. 2. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

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10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per transis	stor					
I _{CBO}	collector-base cut-off	V _{CB} = 50 V; I _E = 0 A; T _{amb} = 25 °C	-	-	50	nA
	current	V_{CB} = 50 V; I _E = 0 A; T _j = 125 °C	-	-	10	μA
I _{EBO}	emitter-base cut-off current	V_{EB} = 6 V; I _C = 0 A; T _{amb} = 25 °C	-	-	50	nA
h _{FE}	DC current gain	V_{CE} = 1 V; I _C = 0.1 mA; T _{amb} = 25 °C	20	-	-	
		V_{CE} = 1 V; I _C = 1 mA; T _{amb} = 25 °C	40	-	-	
		V_{CE} = 1 V; I _C = 10 mA; T _{amb} = 25 °C	80	-	-	
		V_{CE} = 1 V; I _C = 150 mA; t _p ≤ 300 µs; δ ≤ 0.02; T _{amb} = 25 °C	100	-	300	
		V_{CE} = 2 V; I _C = 500 mA; t _p ≤ 300 µs; δ ≤ 0.02; T _{amb} = 25 °C	40	-	-	
OLUUI	collector-emitter saturation voltage	I_{C} = 150 mA; I_{B} = 15 mA; t_{p} ≤ 300 µs; δ ≤ 0.02; T_{amb} = 25 °C	-	-	400	mV
		I_{C} = 500 mA; I_{B} = 50 mA; t_{p} ≤ 300 µs; δ ≤ 0.02; T_{amb} = 25 °C	-	-	750	mV
V _{BEsat}	base-emitter saturation voltage	I_C = 150 mA; I_B = 15 mA; $t_p \le 300 \ \mu$ s; δ ≤ 0.02; T_{amb} = 25 °C	-	-	950	mV
		$I_{C} = 500 \text{ mA}; I_{B} = 50 \text{ mA}; t_{p} \le 300 \mu\text{s};$ $\delta \le 0.02; T_{amb} = 25 ^{\circ}\text{C}$	-	-	1.2	V
t _d	delay time	I _C = 150 mA; I _{Bon} = 15 mA;	-	-	10	ns
t _r	rise time	I _{Boff} = -15 mA; T _{amb} = 25 °C	-	-	25	ns
t _{on}	turn-on time	-	-	-	35	ns
t _s	storage time	-	-	-	200	ns
t _f	fall time	-	-	-	60	ns
t _{off}	turn-off time	-	-	-	250	ns
C _C	collector capacitance	V _{CB} = 10 V; I _E = 0 A; i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C	-	-	8	pF
C _E	emitter capacitance	V _{EB} = 500 mV; I _C = 0 A; f = 1 MHz; T _{amb} = 25 °C	-	-	30	pF
f _T	transition frequency	V _{CE} = 20 V; I _C = 20 mA; f = 100 MHz; T _{amb} = 25 °C	250	-	-	MHz
NF	noise figure	V_{CE} = 5 V; I _C = 100 μA; R _S = 1 kΩ; f = 1 kHz	-	-	4	dB

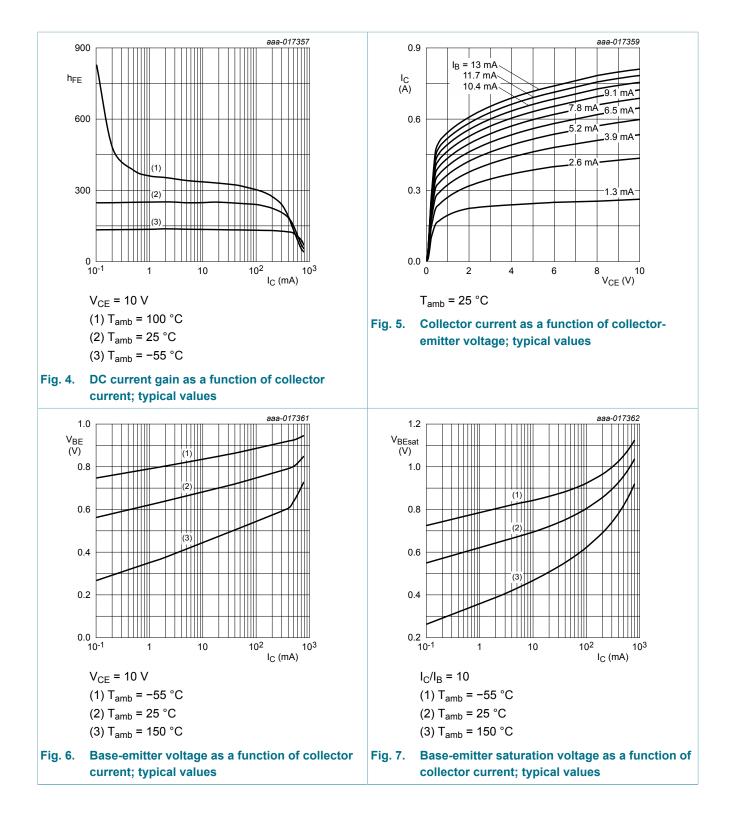
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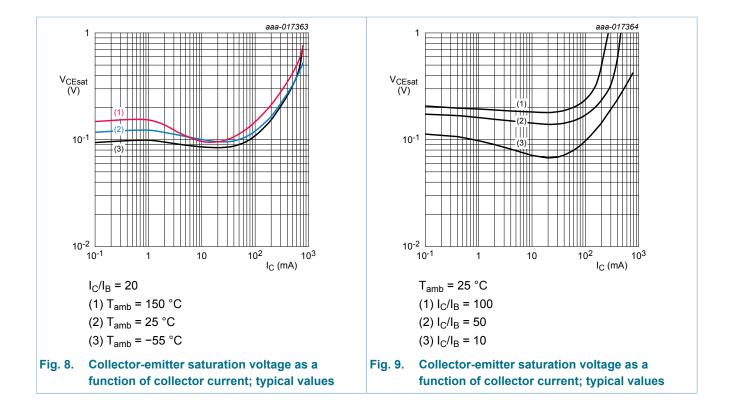
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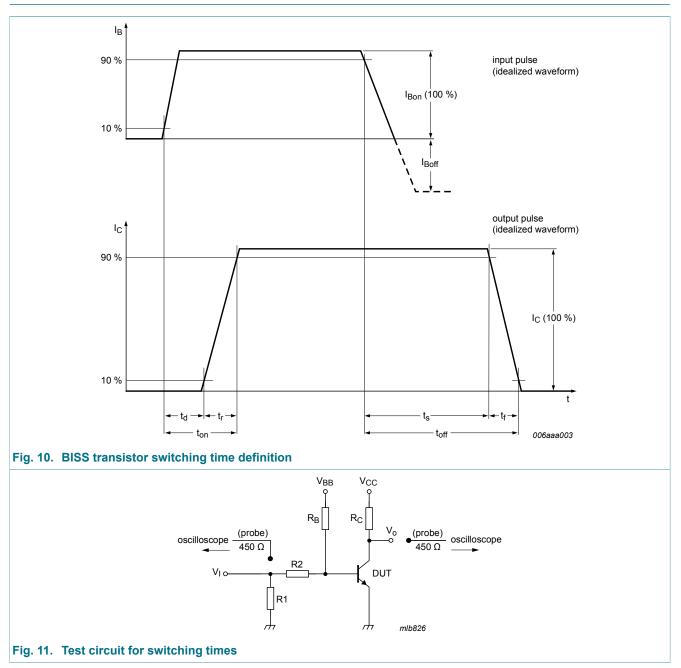
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11. Test information

11.1 Quality information

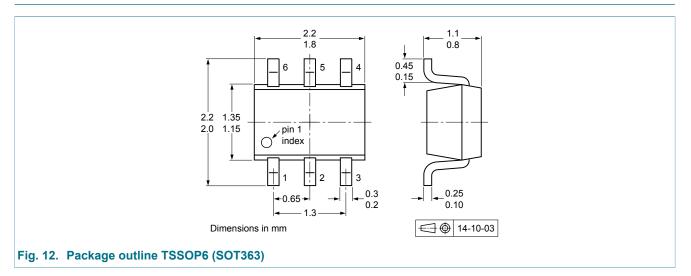
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

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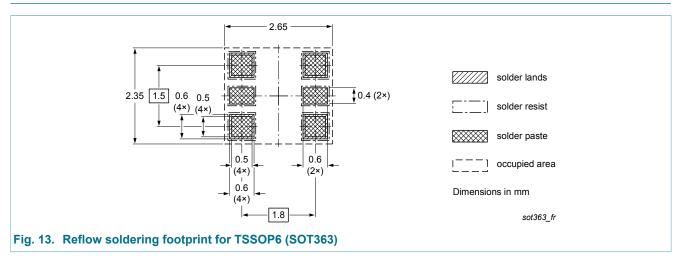
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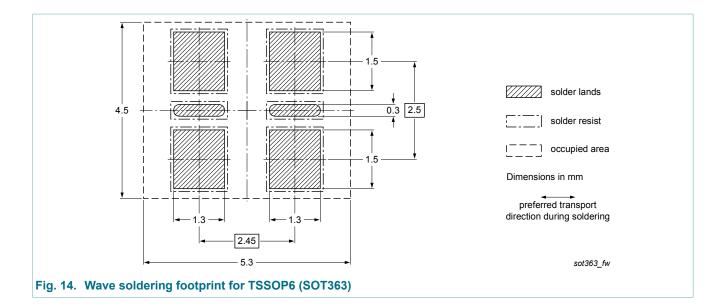
12. Package outline



13. Soldering



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14. Revision history

Table 8. Revision history						
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
PMBT4401YS v.1	20150702	Product data sheet	-	-		

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15. Legal information

15.1 Data sheet status

Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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